Diode Semiconductor Device - Page 1 of 1



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|    | closure Material:   |
|----|---|
| G  | lass  |
| 0  | verall Length:  |
| 0. | 350 inches  |
| т  | erminal Length:   |
| 1. | 000 inches  |
| 0  | verall Diameter:  |
| 0. | 145 inches  |
| F  | unction For Which Designed:   |
| Ze | ener diode  |
| М  | ounting Method:   |
| Т  | erminal   |
| Fe | eatures Provided:   |
| н  | ermetically sealed case   |
| S  | emiconductor Material:  |
| Si | licon   |
| V  | oltage Rating In Volts Per Characteristic:                          |
| 22 | 2.0 regulator voltage   |
| V  | oltage Tolerance In Percent:  |
| -5 | .0/+5.0   |
| С  | urrent Rating Per Characteristic:                                   |
| 50 | 0.00 milliamperes all primaries horsepower metric                   |
| P  | ower Rating Per Characteristic:                                     |
| 5. | 0 watts total device dissipation                                    |
| Μ  | aximum Operating Tempurature Per Measurement Point:                 |
| 20 | 00.0 degrees celsius ambient air                                    |
| Т  | erminal Type And Quantity:  |
| 2  | uninsulated wire lead   |
| S  | pecification Data:  |
| 80 | 0131-release 5750 professional/industrial association specification |
| S  | helf Life:  |
| N  | /a  |
| U  | nit Of Measure:   |
|    |   |
| D  | emilitarization:  |
| Ν  |   |
| Fi | ig:   |
|    | 110a0   |